



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE	Application No.	10/024,475 ✓
	Filing Date	December 12, 2001
	First Named Inventor	Chan-ho PARK
	Group Art Unit	2811
	Examiner Name	Im, Junghwa M.
	Attorney Docket No.	1751-294
Title of the Invention: HIGH VOLTAGE SEMICONDUCTOR DEVICE HAVING HIGH BREAKDOWN VOLTAGE AND METHOD OF FABRICATING THE SAME		

#8/A
And
J. McNeill
3/6/03

AMENDMENT UNDER 37 C.F.R. § 1.111

Assistant Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

In response to the Office Action mailed December 4, 2002, please enter the amendments contained on the following page, which are summarized below.

IN THE CLAIMS:

Please amend claim 1.

Please cancel claim 2 without prejudice or disclaimer.

A marked-up copy of the original text of the amended claim is attached to this amendment. Material inserted is indicated by underlining and material deleted is indicated by brackets.

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